



BJT

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☰ By	Sagoor

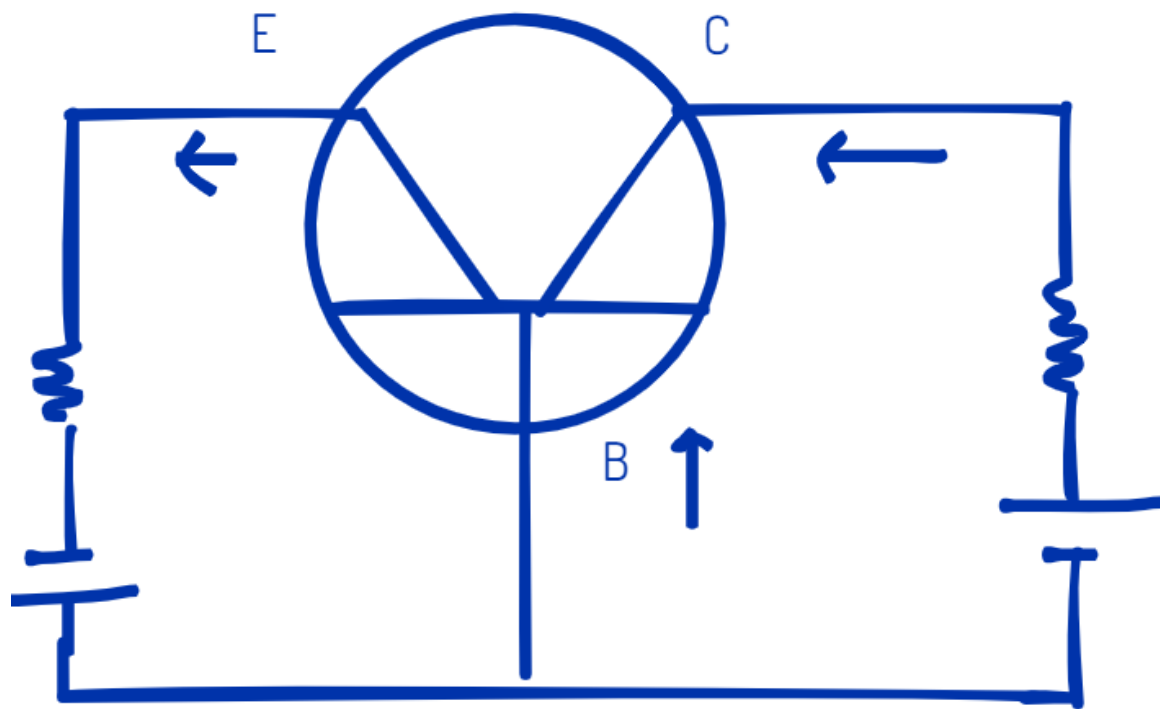
References:

- https://www.youtube.com/watch?v=p3ccfbyyDSQ&list=PLgwYQr3eNLspqSjN26drjIWFZhCgBFfi&index=2&ab_channel=ElectricalEngineeringSolution

Basic Configuration of transistor:

Configuration:

Common Base:



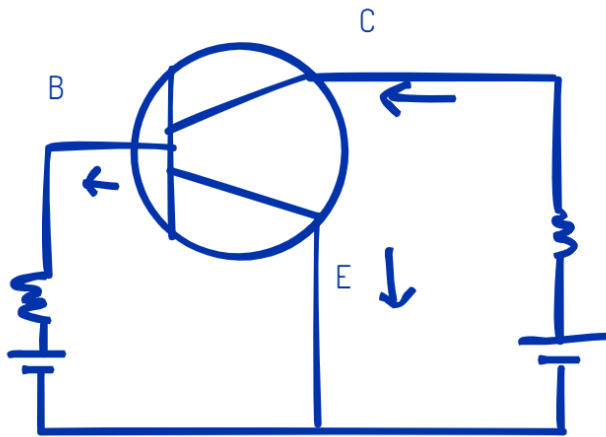
$$I_E = I_C + I_B$$

Amplification factor, $\alpha = I_C / I_E$

$I_C = \alpha \cdot I_E + I_{CBO}$ (reverse saturated current) (perfectly)

$I_C = \alpha \cdot I_E$ (If we ignore I_{CBO})

Common Emitter:



$$I_E = I_B + I_C$$

$$I_C = \alpha I_E + I_{CBO}$$

$$\Rightarrow I_C = \alpha(I_B + I_C) + I_{CBO}$$

$$\Rightarrow I_C(1 - \alpha) = \alpha I_B + I_{CBO}$$

$$\Rightarrow I_C = I_B \left(\frac{\alpha}{1 - \alpha} \right) + \frac{I_{CBO}}{1 - \alpha}$$

$$\Rightarrow I_C = \beta I_B + (\beta + 1) I_{CBO}$$

$$I_E = I_B + I_C$$

Amplification factor, $\beta = I_C / I_B = \alpha / (1 - \alpha)$

$$I_C = \beta I_B + I_{CEO} \text{ (reverse saturated current)}$$

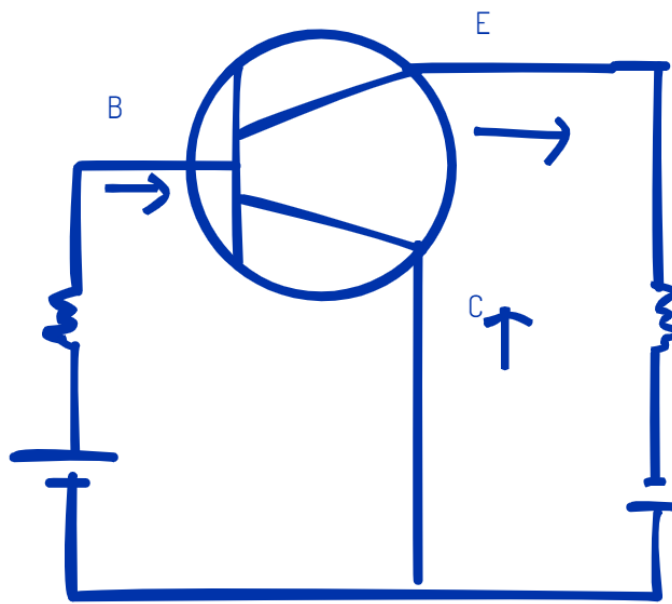
$$\boxed{\alpha = \frac{I_C}{I_E}} \quad \beta = \frac{I_C}{I_B}$$

$$= \frac{I_C}{I_E - I_C}$$

$$= \frac{\frac{I_C}{I_E}}{1 - \frac{I_C}{I_E}}$$

$$= \frac{\alpha}{1 - \alpha}$$

Common Collector:



$$I_C = I_B \cdot \gamma + \gamma \cdot I_{BE0}$$

$$\gamma = 1 + \beta = 1 / (1 - \alpha)$$

$$\gamma = \frac{I_E}{I_B}$$

$$= \frac{I_E}{I_E - I_C} \quad [\text{div. by } I_E]$$

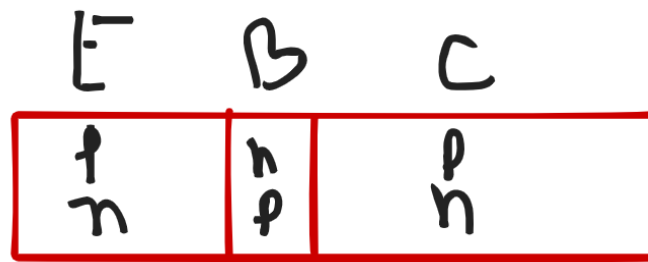
$$= \frac{1}{1 - \alpha}$$

$$= \frac{1 - \alpha + \alpha}{1 - \alpha}$$

$$= \beta + 1$$

BJT

BJT → Bipolar Junction Transistor



3 Part:

- Base → width → light, doping → minimum
- Emitter → width → medium, doping → maximum
- Collector → width → large, doping → medium

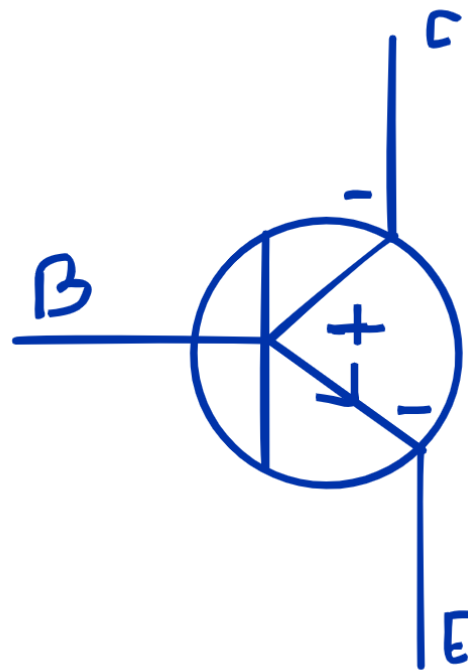
Width : $C > E > B$

Doping: $E > C > B$

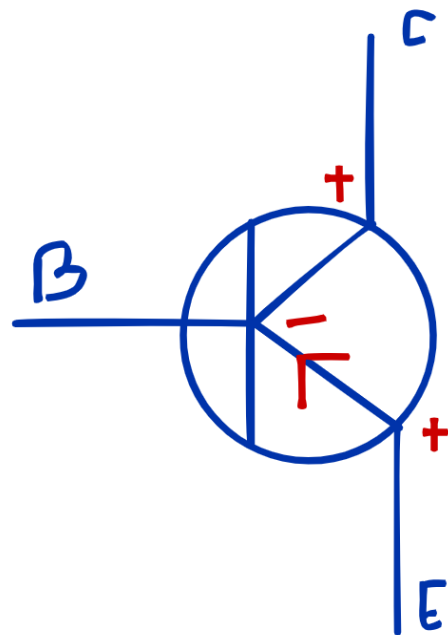
Can be n-p-n or p-n-p.

How to recognize that ?

→ By observing the direction of flowing of the current. Current flows from **positive to negative**.



Current flows
+ to -
So, it's n-p-n



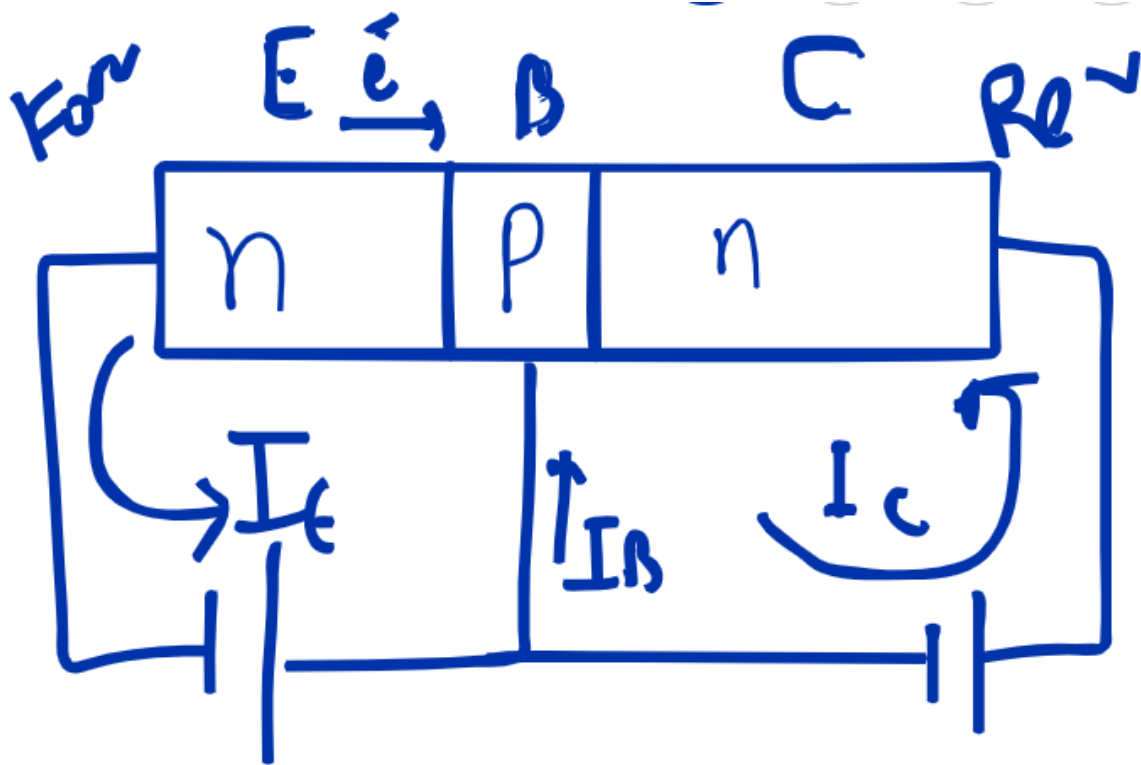
P-N-P transistor

BJT Working:

- n-p-n uses more than p-n-p (commercially)
 - n-p-n has
 - more electron
 - more movability

Junction 1 (E-B)	Junction 2 (C-B)	Mode
Forward	Reverse	Active (amplifier)
Forward	Forward	Saturated
Reverse	Reverse	Cut off
Reverse	Forward	Inverted/ Reverse active (rare use)

Active mode :



$$I_B + I_C = I_E$$

$$I_E \approx I_C$$

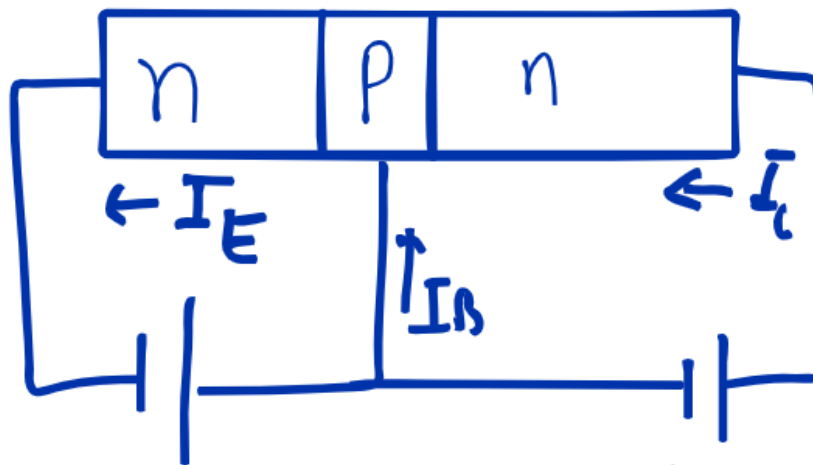
$$I_B + I_C = I_E$$

$$I_E = I_C$$

BJT as an amplifier :

- E-B \rightarrow input

- C-B → Output



$$I_C = I_B = I$$

$$V_i = V_{EB} = I R_{EB} \dots (i)$$

$$V_o = V_{CB} = I R_{CB} \dots (ii)$$

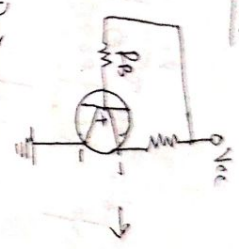
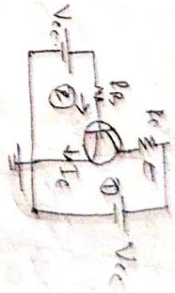
$$\Rightarrow \frac{V_o}{V_i} = \frac{R_{CB}}{R_{EB}} \quad R_{CB} \gg R_{EB} \quad V_o \gg V_i$$

BJT as a switch:

....

DC Biasing

* Fixed Bias:

Loop (1) →

$$-V_{cc} - R_C I_C + V_{CE} = 0$$

$$\Rightarrow V_{CE} = V_{cc} - R_C I_C$$

Loop (2):

$$-V_{cc} + R_B I_B + V_{BE} = 0$$

$$\Rightarrow I_B = \frac{V_{cc} - V_{BE}}{R_B}$$

$$I_C = \beta I_B + (\beta + 1) I_B$$

At saturation:

$$V_{CE} = 0$$

$$I_C = \frac{V_{cc}}{R_C + R_E}$$

At cut off:

$$I_C = 0$$

$$V_{CE} = V_{cc}$$

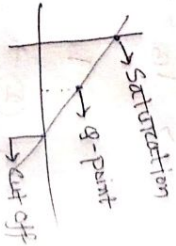
Stability factor $S = \beta + 1$, $S' = \frac{-\beta}{R_B}$

* Saturation factor $S = \beta + 1$, $S' = \frac{-\beta}{R_B}$

$I_C > I_{C(sat)} \rightarrow$ biased in saturation region

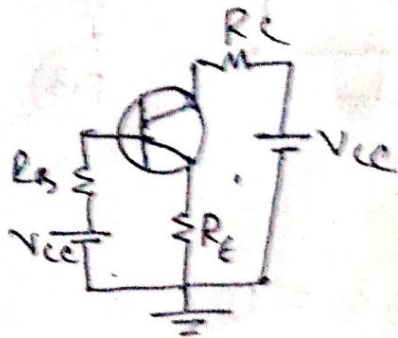
$I_C < I_{C(sat)} \rightarrow$ " " linear region

$I_C = I_{C(sat)} \rightarrow$ " " cut off region



AS142101008M

* Emitter Bias :



W800101008M

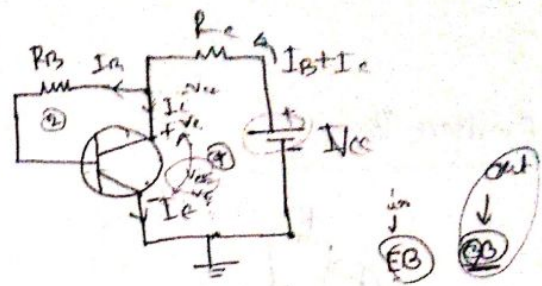
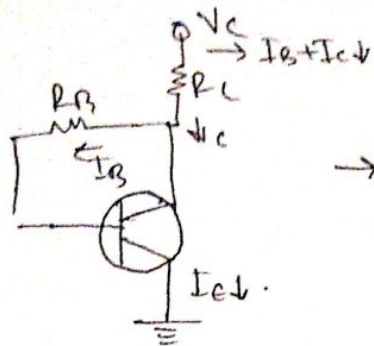
$$-V_{CE} + R_C I_C + R_E I_E + V_{CE} = 0$$

$$\Rightarrow V_{CE} = V_{CC} - R_C I_C - R_E I_E$$

$$-V_{CC} + I_B R_B + V_{BE} + I_E R_E = 0$$

$$\Rightarrow I_B = \frac{V_{CC} - V_{BE}}{R_B + (\beta + 1) R_E}$$

* Collector feedback:



Loop (1) \rightarrow

$$-V_{CC} + (I_B + I_C)R_C + I_B R_B + V_{BE} = 0$$

$$\Rightarrow I_B = \frac{V_{CC} - V_{BE}}{R_B + (\beta + 1)R_C}$$

Loop (2) \rightarrow

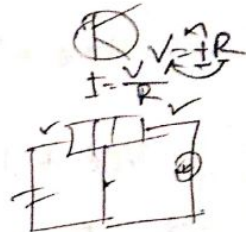
$$-V_{CC} + (I_B + I_C)R_C + V_{CE} = 0$$

$$\Rightarrow -V_{CE} + I_B (1 + \beta)R_C + V_{CE} = 0$$

$$\Rightarrow V_{CE} = V_{CC} - I_B R_C (1 + \beta)$$

$$V_{CE} = V_{CC} - (I_C R_C) \quad (\beta \gg 1)$$

$$V_{CE} = V_{CC} - R_C (I_C + I_B)$$



* $\beta_{DC} \rightarrow$ varies directly with temperature

$V_{BE} \rightarrow$ varies inversely with temperature

$\uparrow \uparrow \quad \beta_{DC} \uparrow \quad I_C \uparrow \quad R_C \uparrow$
 $\downarrow \downarrow \quad V_{BE} \downarrow \quad I_B \uparrow \quad R_B \downarrow$

\rightarrow Not sure \approx

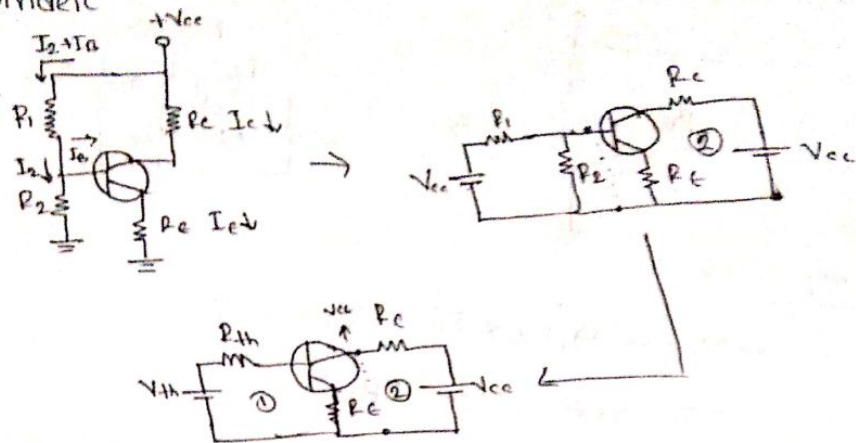
* ~~Stability~~ factor, $S = \frac{(\beta + 1)(1 + R_B/R_C)}{(\beta + 1) + (R_B/R_C)}$

Stability

$$S = (\beta + 1) \frac{1 + R_B/R_C}{(\beta + 1) + (R_B/R_C)}$$

W8001010HSV

* Voltage Divider



$$R_{th} = R_1 || R_2 \quad V_{th} = V_{cc} \frac{R_2}{R_1 + R_2}$$

KVL in Loop (1),

$$-V_{th} + R_{th} I_B + V_{BE} + I_E R_E = 0$$

$$\Rightarrow I_B = \frac{V_{th} - V_{BE}}{R_{th} + (\beta + 1) R_E}$$

Q-point (I_C, V_{CE})

$$I_C = \beta I_B + (\beta + 1) I_{CBO}$$

KVL in Loop (2) →

$$-V_{cc} + R_C I_C + I_E R_E + V_{CE} = 0$$

$$\Rightarrow V_{CE} = V_{cc} - I_C R_C - I_E R_E$$

$$= V_{cc} - I_C (R_C + R_E) \quad [\text{when } \beta \gg 1]$$

Stability Factor:

$$S = \frac{dI_C}{dI_{CBO}} = \frac{(\beta + 1) (R_{th} / R_E)}{(\beta + 1) + \frac{R_{th}}{R_E}}$$

Stability Factor:

The rate of change of **collector current w.r.t** to the leakage current of constant input voltage and amplification factor is called stability factor.

$$S = \frac{dI_C}{dI_{CBO}}$$

$$S' = \frac{dI_C}{dV_{BE}}$$

$$S'' = \frac{dI_C}{d\beta}$$